

**TRIPLE DIFFUSED PLANER TYPE
HIGH VOLTAGE, HIGH SPEED SWITCHING**

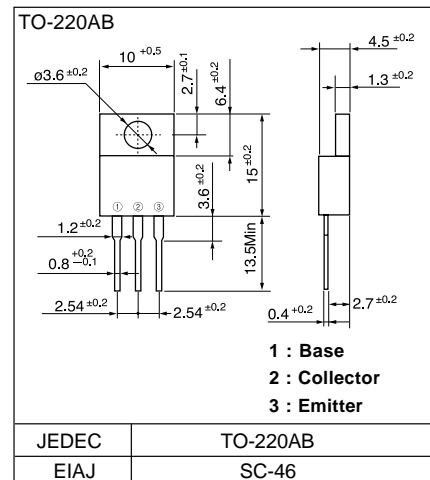
■ **Features**

- High voltage, High speed switching
- High reliability

■ **Applications**

- Switching regulators
- Ultrasonic generators
- High frequency inverters
- General purpose power amplifiers

■ **Outline Drawings**



■ **Maximum ratings and characteristics**

● **Absolute maximum ratings (Tc=25°C unless otherwise specified)**

Item	Symbol	Ratings	Unit
Collector-Base voltage	V _{CB0}	450	V
Collector-Emitter voltage	V _{CEO}	400	V
Collector-Emitter voltage	V _{CEO(SUS)}	400	V
Emitter-Base voltage	V _{EBO}	7	V
Collector current	I _C	3	A
Base current	I _B	1	A
Collector power dissipation	P _C	40	W
Operating junction temperature	T _j	+150	°C
Storage temperature	T _{stg}	-45 to +150	°C

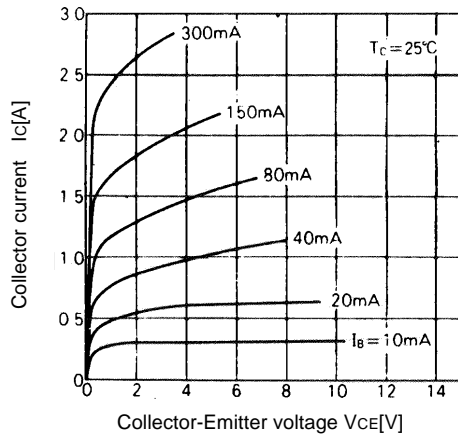
● **Electrical characteristics (Tc = 25°C unless otherwise specified)**

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Base voltage	V _{CB0}	I _{CBO} = 0.1mA	450			V
Collector-Emitter voltage	V _{CEO}	I _{CEO} = 10mA	400			V
Collector-Emitter voltage	V _{CEO(SUS)}	I _C = 0.5A	400	-		V
Emitter-Base voltage	V _{EBO}	I _{EBO} = 0.1mA	7	-		V
Collector-Base leakage current	I _{CBO}	V _{CB0} = 450V		-	0.1	mA
Emitter-Base leakage current	I _{EBO}	V _{EBO} = 7V		-	0.1	mA
D.C. current gain	h _{FE}	I _C = 0.5A, V _{CE} = 5V	20		50	
Collector-Emitter saturation voltage	V _{CE(Sat)}	I _C = 1A, I _B = 0.2A	0.1		0.3	V
Base-Emitter saturation voltage	V _{BE(Sat)}		0.8		0.9	V
*1	t _{on}	I _C = 3A, I _{B1} = 0.6A			1.5	μs
Switching time	t _{stg}	I _{B2} = -0.6A, R _L = 20 ohm			2.0	μs
	t _f	P _w = 20μs Duty<2%			0.8	μs

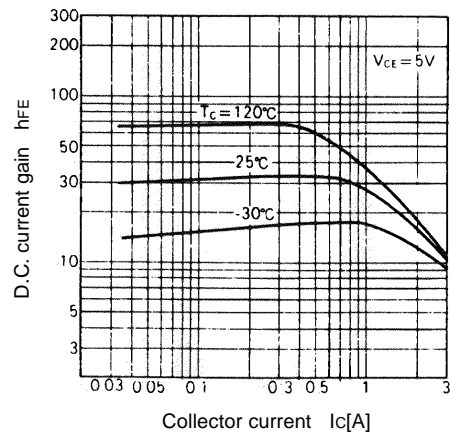
● **Thermal characteristics**

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal resistance	R _{th(j-c)}	Junction to case			3.0	°C/W

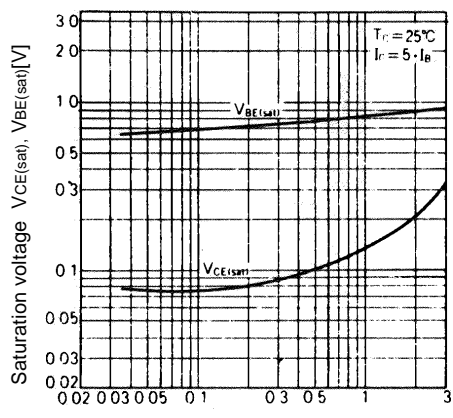
Characteristics



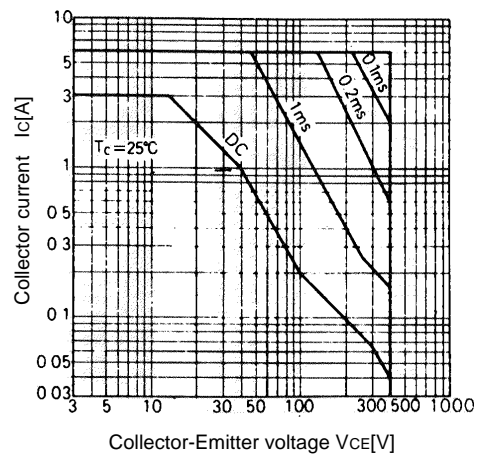
Collector Output Characteristics



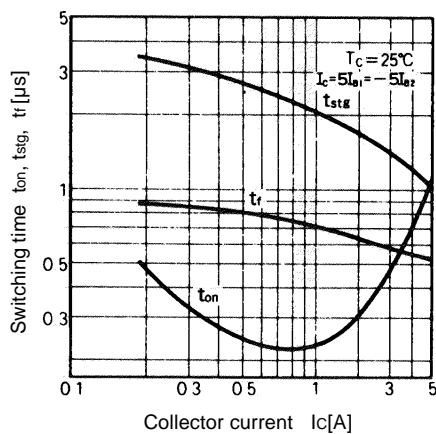
DC Current Gain



Base and Collector Saturation Voltage



Safe Operating Area



Switching Time

*1 Switching Time Test Circuit

